

1N4148W-HF

Reverse Voltage: 100 V

Forward Current: 150mA

RoHS Device

Halogen Free

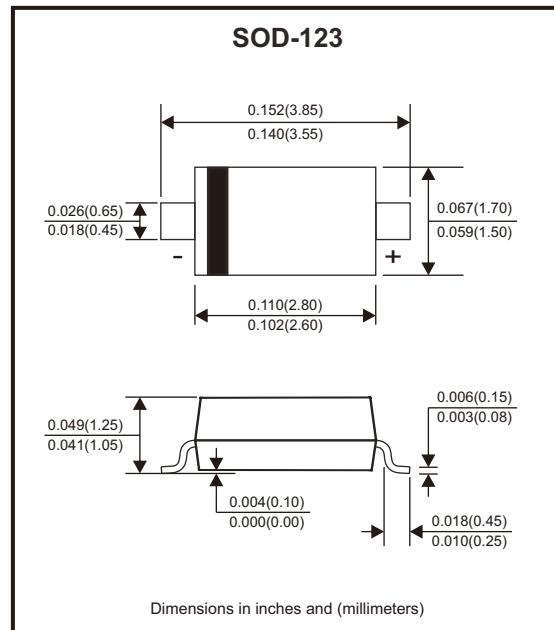


Features

- Fast switching device ($T_{rr} < 4.0\text{nS}$).
- Power dissipation of 500mW.
- High stability and high reliability.
- Low reverse leakage.

Mechanical data

- Case: SOD-123, molded plastic.
- Polarity: Color band denotes cathode end.
- Epoxy UL: 94V-0.
- Mounting position: Any.



Circuit Diagram



Maximum Rating (at $T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Peak reverse voltage	V_{RM}	100	V
Power dissipation	P_D	500	mW
Average rectified current	I_O	150	mA
Non-repetitive peak forward current	I_{FIM}	300	mA
Peak forward surge current @ $t_p=1\mu\text{s}$, $T_a=25^\circ\text{C}$	I_{FSM}	2	A
Thermal resistance from junction to ambient	$R_{\theta JA}$	250	$^\circ\text{C}/\text{W}$
Operating junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature range	T_{STG}	-65 to +150	$^\circ\text{C}$

Note: Valid provided that electrodes are kept at ambient temperature.

SMD Switching Diode

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SMD Diode Specialist

Electrical Characteristics (at $T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Breakdown voltage	$I_R = 100\mu\text{A}$	B_V	100			V
Reverse leakage current	$V_R = 20\text{V}$	I_R			25	nA
	$V_R = 20\text{V}, T_J=150^\circ\text{C}$				50	μA
	$V_R = 75\text{V}$				5	
Forward voltage	$I_F = 10\text{mA}$	V_F			1.00	V
	$I_F = 100\text{mA}$				1.25	
Capacitance	$V_R = 0\text{V}, f = 1\text{MHz}$	C			4	pF
Reverse recovery time	$I_F = I_R = 10\text{mA}, I_{rr} = 0.1 \times I_R$ $R_L = 100\Omega$	T_{RR}			4	nS

Rating and Characteristic Curves (1N4148W-HF)

Fig.1 - Forward Characteristics

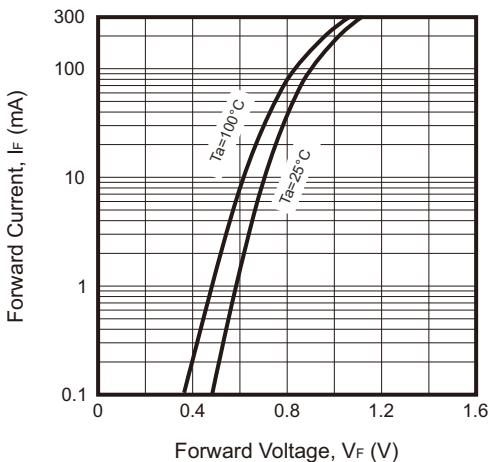


Fig.2 - Reverse Characteristics

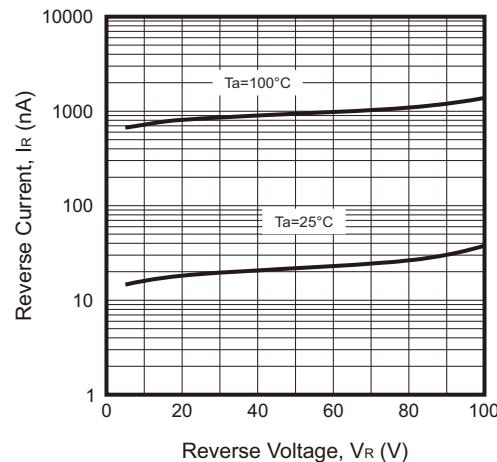


Fig.3 - Capacitance Characteristics

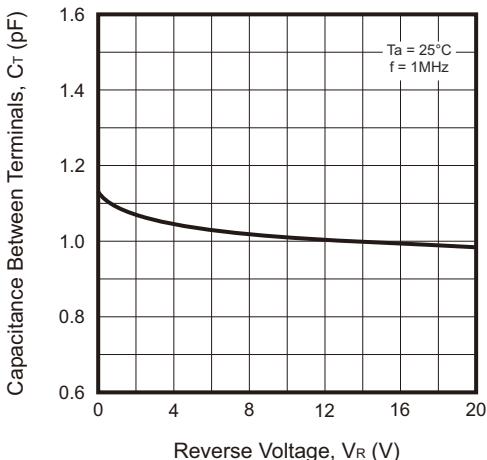
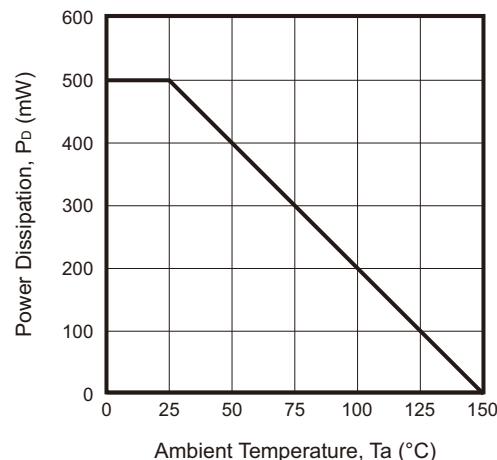


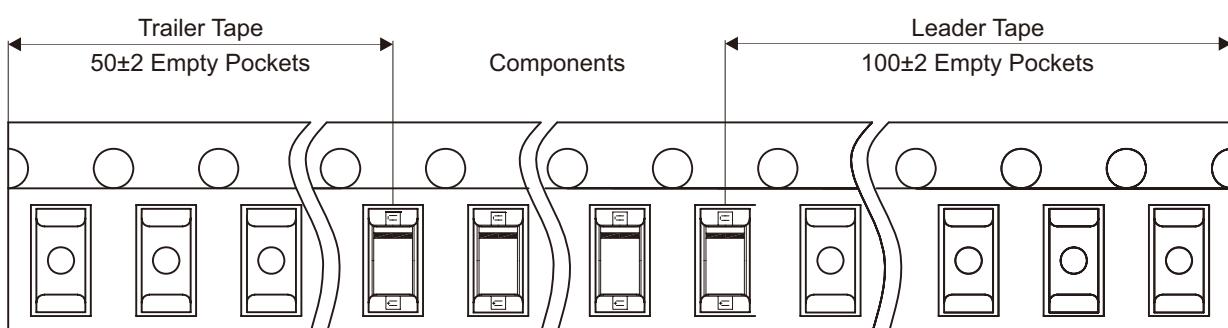
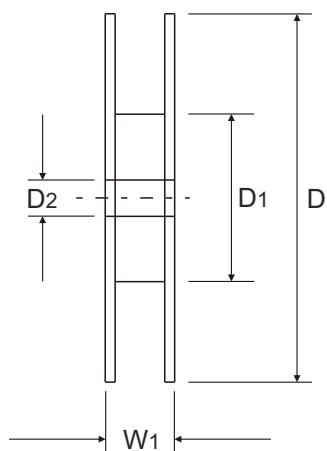
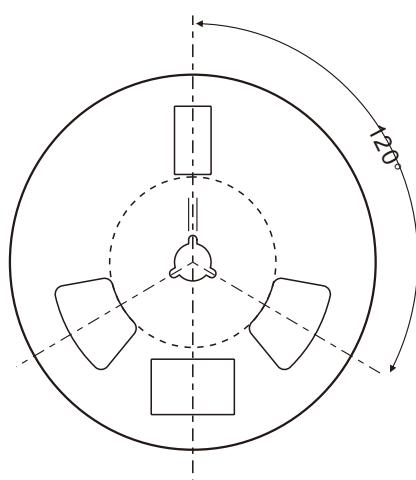
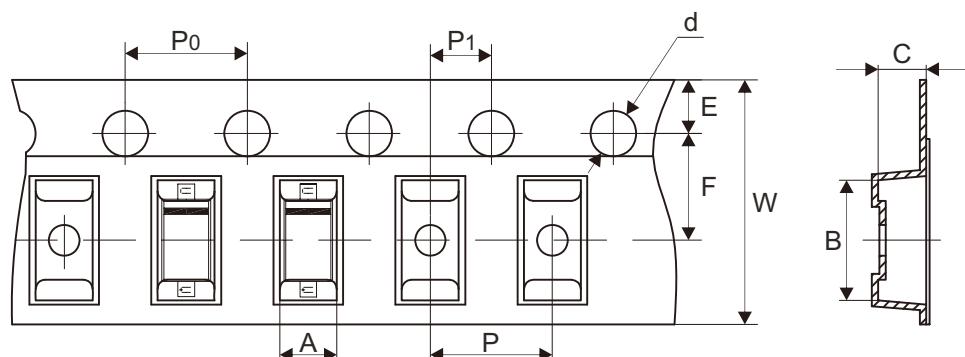
Fig.4 - Power Derating Curve



Company reserves the right to improve product design , functions and reliability without notice.

REV:A

Reel Taping Specification



	SYMBOL	A	B	C	d	D	D ₁	D ₂
SOD-123	(mm)	1.85 ± 0.05	3.94 ± 0.05	1.57 ± 0.05	1.55 ± 0.10	178.00 ± 2.00	54.40 ± 1.00	13.00 ± 1.00
	(inch)	0.073 ± 0.002	0.155 ± 0.002	0.062 ± 0.002	0.061 ± 0.004	7.008 ± 0.079	2.142 ± 0.039	0.512 ± 0.039

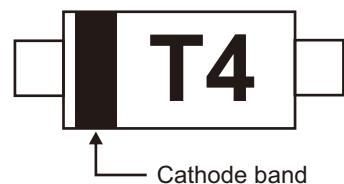
	SYMBOL	E	F	P	P ₁	P ₀	W	W ₁
SOD-123	(mm)	1.75 ± 0.10	3.50 ± 0.10	4.00 ± 0.10	2.00 ± 0.10	4.00 ± 0.10	8.00 + 0.06 - 0.10	12.30 ± 1.00
	(inch)	0.069 ± 0.004	0.138 ± 0.004	0.157 ± 0.004	0.079 ± 0.004	0.157 ± 0.004	0.315 + 0.002 - 0.004	0.484 ± 0.039

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REV:A

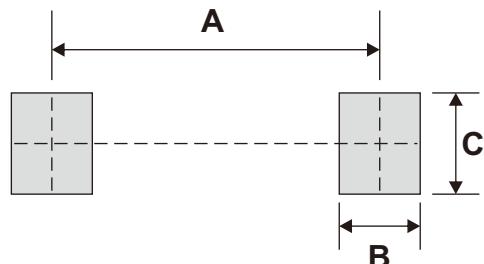
Marking Code

Part Number	Marking Code
1N4148W-HF	T4



Suggested PAD Layout

SIZE	SOD-123	
	(mm)	(inch)
A	3.24	0.128
B	0.80	0.031
C	1.00	0.039



Note: 1.The pad layout is for reference purposes only.

Standard Packaging

Case Type	REEL PACK	
	REEL (pcs)	Reel Size (inch)
SOD-123	3,000	7

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